

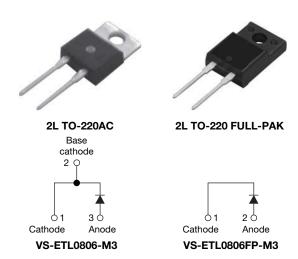
Vishay Semiconductors

COMPLIANT

HALOGEN

FREE

# Ultrafast Rectifier, 8 A FRED Pt®



PRODUCT SUMMARY				
Package	2L TO-220AC, 2L TO-220FP			
I <sub>F(AV)</sub>	8 A			
V <sub>R</sub>	600 V			
V <sub>F</sub> at I <sub>F</sub>	1.1 V			
t <sub>rr</sub> (typ.)	65 ns			
T <sub>J</sub> max.	175 °C			
Diode variation	Single die			

#### **FEATURES**

- State of the art low forward voltage drop
- Ultrafast recovery time
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- True 2 pin package
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Designed and qualified according to JEDEC-JESD47

### **DESCRIPTION**

State of the art, ultralow  $V_F$ , soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

#### **APPLICATIONS**

AC-DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	$V_{RRM}$		600	V	
Average rectified forward current in DC FULL-PAK	I <sub>F(AV)</sub>	T <sub>C</sub> = 155 °C	- 8	А	
		T <sub>C</sub> = 134 °C	0		
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	120		
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C	

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA		-	-	
Forward voltage V <sub>F</sub>	V	I <sub>F</sub> = 8 A		0.97	1.07	V
	٧F	I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	0.84	0.90	
Reverse leakage current	_	$V_R = V_R$ rated	-	0.01	9	
Reverse leakage current		T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	5	50	μA
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	6	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body - 8 -		nH		

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# **VS-ETL0806-M3, VS-ETL0806FP-M3**

Vishay Semiconductors Ultrafast Rectifier, 8 A FRED Pt®



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
Reverse recovery time	t <sub>rr</sub>	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		1	65	100	
		$I_F = 8 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	150	250	
		T <sub>J</sub> = 25 °C	$I_F = 8 \text{ A}$ $dI_F/dt = 390 \text{ A/}\mu\text{s}$ $V_R = 390 \text{ V}$	-	180	-	ns A nC
		T <sub>J</sub> = 125 °C		-	240	-	
Peak recovery current I <sub>RRM</sub>		T <sub>J</sub> = 25 °C		-	15	-	
	IRRM	T <sub>J</sub> = 125 °C		-	19	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	1500	-	
		T <sub>J</sub> = 125 °C		-	2400	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C
Thermal resistance,	В		-	2.0	2.6	
junction to case FULL-PAK	$R_{thJC}$		=	4.6	5.5	
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-	
M/.:.li			-	2	-	g
Weight			-	0.07	-	OZ.
Mounting torque			6	_	12	kgf · cm
			(5)		(10)	(lbf · in)
Modeing dovice		Case style 2L TO-220AC	ETL0806			
Marking device		Case style 2L TO-220 FULL-PAK	ETL0806FP			



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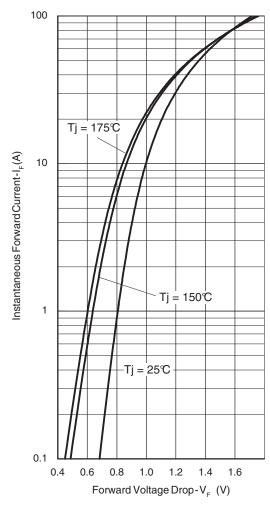


Fig. 1 - Typical Forward Voltage Drop Characteristics

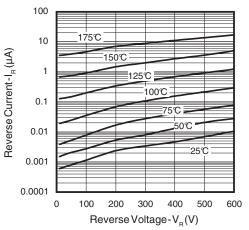


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

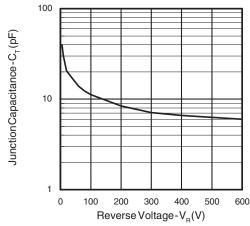


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

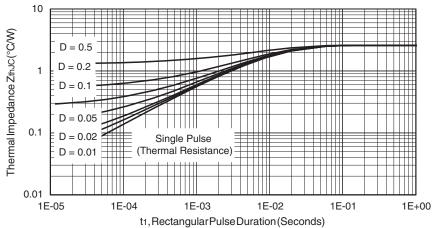


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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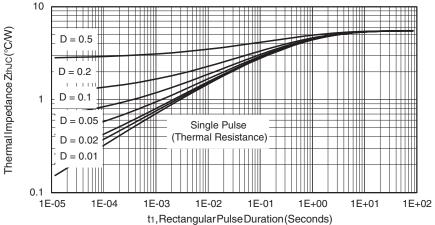


Fig. 5 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (FULL-PAK)

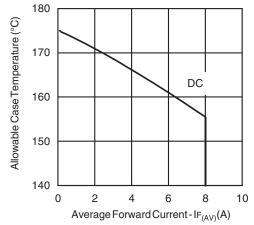


Fig. 6 - Maximum Allowable Case Temperature vs.
Average Forward Current

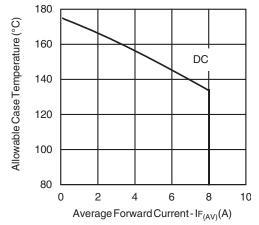


Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)

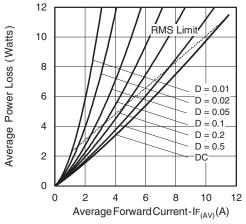


Fig. 8 - Forward Power Loss Characteristics





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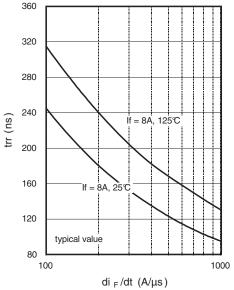


Fig. 9 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt

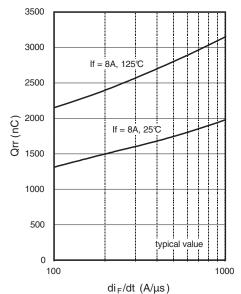


Fig. 10 - Typical Stored Charge vs. dl<sub>F</sub>/dt

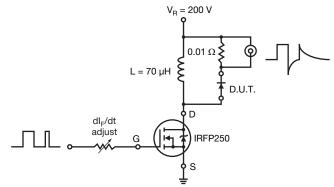
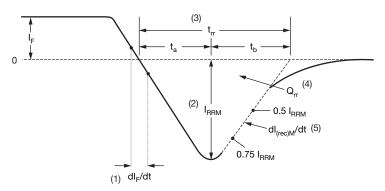


Fig. 11 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $t_{rr}$  reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75  $I_{RRM}$  and 0.50  $I_{RRM}$ extrapolated to zero current.
- (4) Q<sub>rr</sub> area under curve defined by t<sub>rr</sub>
- (5)  $dI_{(rec)M}/dt$  peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 12 - Reverse Recovery Waveform and Definitions

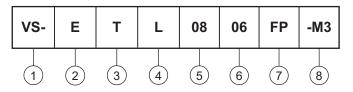
## **VS-ETL0806-M3, VS-ETL0806FP-M3**

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### **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

Circuit configuration:

E = Single diode

T = TO-220

L = Hyperfast recovery time

Current code: 08 = 80 A

Voltage code: 06 = 600 V

• None = TO-220

• FP = FULL-PAK

8 Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-ETL0806-M3	50	1000	Antistatic plastic tube		
VS-ETL0806FP-M3	50	1000	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions	2L TO-220AC	www.vishay.com/doc?95259		
Differisions	2L TO-220 FULL-PAK	www.vishay.com/doc?95260		
Part marking information	2L TO-220AC	www.vishay.com/doc?95391		
Part marking information	2L TO-220 FULL-PAK	www.vishay.com/doc?95392		





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